



STD90N4F3, STI90N4F3 STP90N4F3, STU90N4F3

N-channel 40 V, 5.0 mΩ, 80 A, DPAK, TO-220, IPAK, I²PAK
STripFET™ III Power MOSFET

Features

Type	V _{DSS}	R _{DS(on)} max	I _D	P _w
STD90N4F3	40 V	< 5.8 mΩ	80 A	110 W
STI90N4F3	40 V	< 6.2 mΩ	80 A	110 W
STP90N4F3	40 V	< 6.2 mΩ	80 A	110 W
STU90N4F3	40 V	< 6.2 mΩ	80 A	110 W

- Standard threshold drive
- 100% avalanche tested

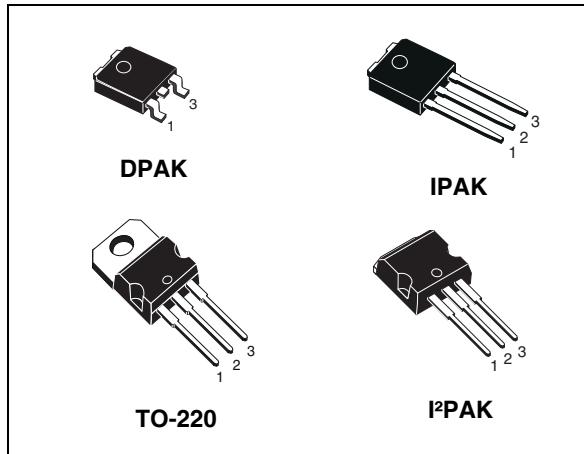


Figure 1. Internal schematic diagram

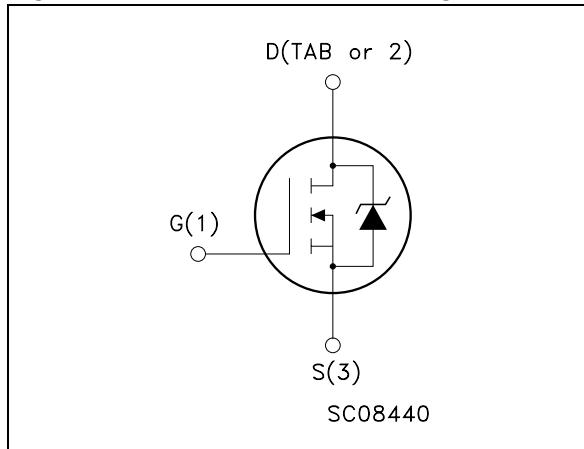


Table 1. Device summary

Order codes	Marking	Package	Packaging
STD90N4F3	90N4F3	DPAK	Tape & reel
STI90N4F3	90N4F3	I ² PAK	Tube
STP90N4F3	90N4F3	TO-220	Tube
STU90N4F3	90N4F3	IPAK	Tube

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1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{DS}	Drain-source voltage ($V_{GS}=0$)	40	V
V_{GS}	Gate-source voltage	± 20	V
$I_D^{(1)}$	Drain current (continuous) at $T_C = 25^\circ\text{C}$	80	A
I_D	Drain current (continuous) at $T_C = 100^\circ\text{C}$	65	A
$I_{DM}^{(2)}$	Drain current (pulsed)	320	A
P_{TOT}	Total dissipation at $T_C = 25^\circ\text{C}$	110	W
	Derating factor	0.73	W/ $^\circ\text{C}$
$dv/dt^{(3)}$	Peak diode recovery voltage slope	8	V/ns
$E_{AS}^{(4)}$	Single pulse avalanche energy	400	mJ
T_j T_{stg}	Operating junction temperature Storage temperature	-55 to 175	$^\circ\text{C}$

1. Current limited by package
2. Pulse width limited by safe operating area
3. $I_{SD} \leq 80\text{ A}$, $di/dt \leq 400\text{A}/\mu\text{s}$, $V_{DS} \leq V_{(\text{BR})DSS}$, $T_j \leq T_{jmax}$
4. Starting $T_j = 25^\circ\text{C}$, $I_D = 40\text{A}$, $V_{DD} = 30\text{V}$

Table 3. Thermal resistance

Symbol	Parameter	Value			Unit
		TO-220 I ² PAK	IPAK	DPAK	
$R_{thj-case}$	Thermal resistance junction-case max	1.36			$^\circ\text{C/W}$
R_{thj-a}	Thermal resistance junction-ambient max	62.5	100		$^\circ\text{C/W}$
$R_{thj-pcb}^{(1)}$	Thermal resistance junction-ambient max			50	$^\circ\text{C/W}$
T_I	Maximum lead temperature for soldering purpose	300	275		$^\circ\text{C}$

1. When mounted on 1inch² FR-4 2Oz Cu board

2 Electrical characteristics

($T_{CASE} = 25^\circ C$ unless otherwise specified)

Table 4. Static

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{(BR)DSS}$	Drain-source breakdown voltage	$I_D = 250 \mu A, V_{GS} = 0$	40			V
I_{DSS}	Zero gate voltage drain current ($V_{GS} = 0$)	$V_{DS} = \text{Max rating}, V_{GS} = \text{Max rating}, T_c = 125^\circ C$			10 100	μA μA
I_{GSS}	Gate body leakage current ($V_{DS} = 0$)	$V_{GS} = \pm 20 V$			± 200	nA
$V_{GS(th)}$	Gate threshold voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	2		4	V
$R_{DS(on)}$	Static drain-source on resistance	$V_{GS} = 10 V, I_D = 40 A$ for DPAK		5.0	5.8	$m\Omega$
		$V_{GS} = 10 V, I_D = 40 A$ for IPAK, I ² PAK, TO-220		5.4	6.2	$m\Omega$

Table 5. Dynamic

Symbol	Parameter	Test conditions	Min	Typ.	Max.	Unit
$g_{fs}^{(1)}$	Forward transconductance	$V_{DS} = 25 V, I_D = 40 A$	-	100		S
C_{iss} C_{oss} C_{rss}	Input capacitance Output capacitance Reverse transfer capacitance	$V_{DS} = 25 V, f = 1 MHz, V_{GS} = 0$		2200 580 40		pF pF pF
Q_g Q_{gs} Q_{gd}	Total gate charge Gate-source charge Gate-drain charge	$V_{DD} = 20 V, I_D = 80 A$ $V_{GS} = 10 V$ (see Figure 14)		40 11 8	54	nC nC nC

1. Pulsed: pulse duration = 300µs, duty cycle 1.5%

Table 6. Switching on/off (inductive load)

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$t_{d(on)}$ t_r	Turn-on delay time Rise time	$V_{DD}=20\text{ V}$, $I_D=40\text{ A}$, $R_G=4.7\text{ }\Omega$, $V_{GS}=10\text{ V}$ (see Figure 16)	-	15 50	-	ns ns
$t_{d(off)}$ t_f	Turn-off delay time Fall time	$V_{DD}=20\text{ V}$, $I_D=40\text{ A}$, $R_G=4.7\text{ }\Omega$, $V_{GS}=10\text{ V}$ (see Figure 16)	-	40 15	-	ns ns

Table 7. Source drain diode

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{SD} $I_{SDM}^{(1)}$	Source-drain current Source-drain current (pulsed)		-		80 320	A A
$V_{SD}^{(2)}$	Forward on voltage	$I_{SD}=80\text{ A}$, $V_{GS}=0$	-		1.5	V
t_{rr} Q_{rr} I_{RRM}	Reverse recovery time Reverse recovery charge Reverse recovery current	$I_{SD}=80\text{ A}$, $di/dt = 100\text{ A}/\mu\text{s}$, $V_{DD}=30\text{ V}$, $T_j=150^\circ\text{C}$ (see Figure 15)	-	45 60 2.8		ns nC A

1. Pulse width limited by safe operating area
2. Pulsed: pulse duration = 300 μs , duty cycle 1.5%

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

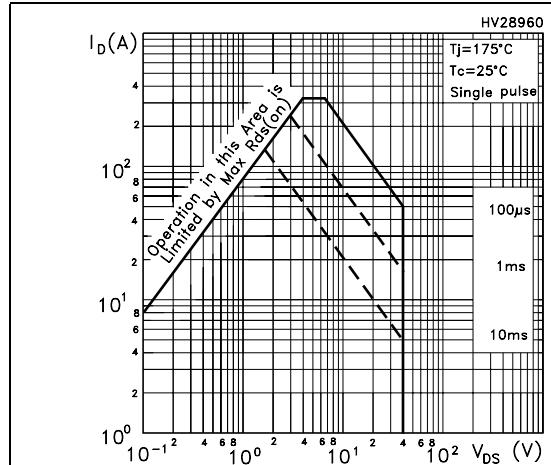


Figure 3. Thermal impedance

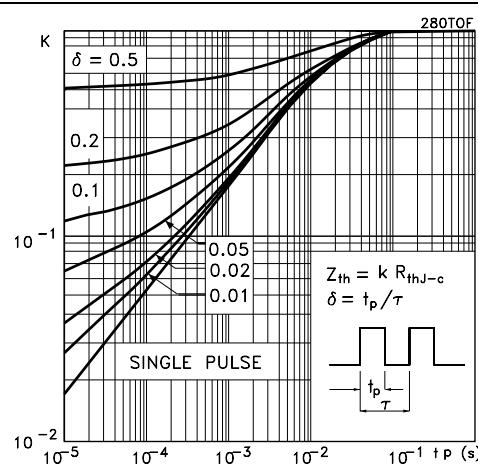


Figure 4. Output characteristics

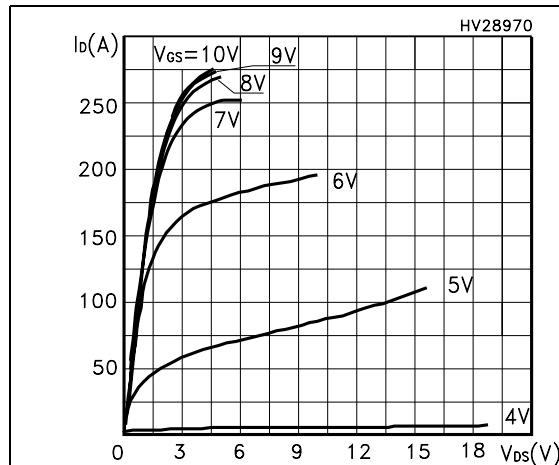


Figure 5. Transfer characteristics

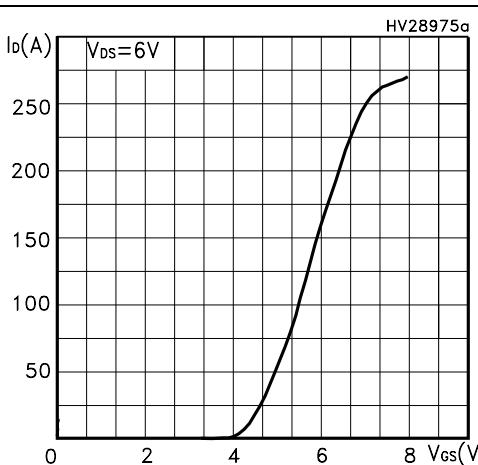


Figure 6. Static drain-source on resistance

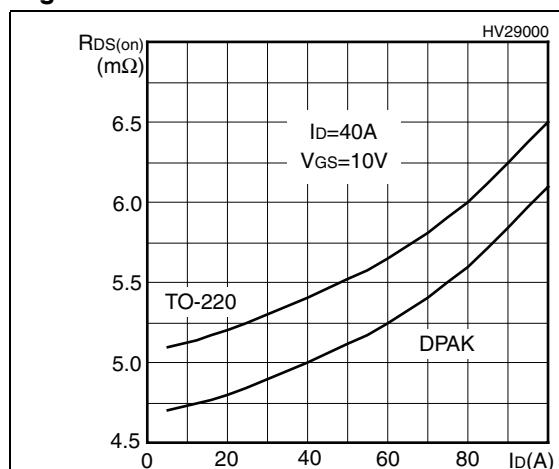


Figure 7. Normalized BVDSS vs temperature

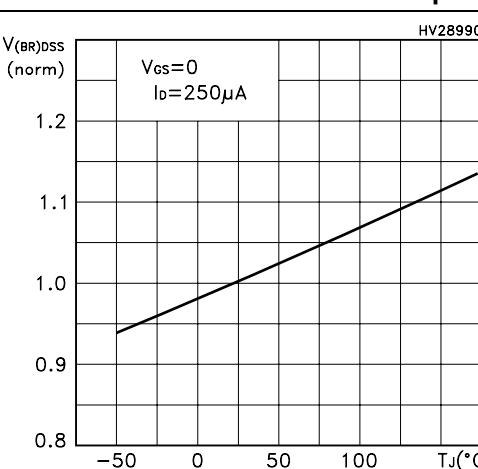
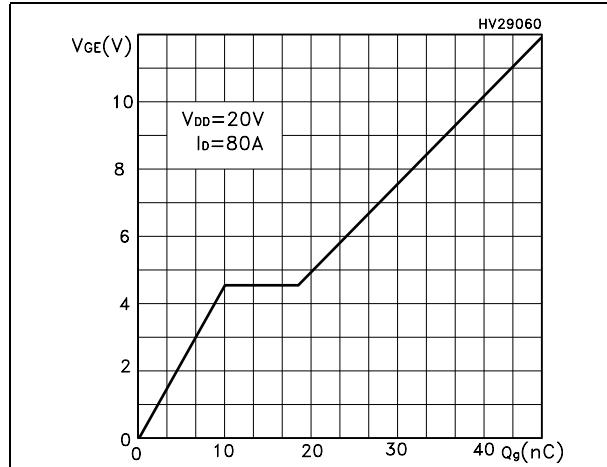
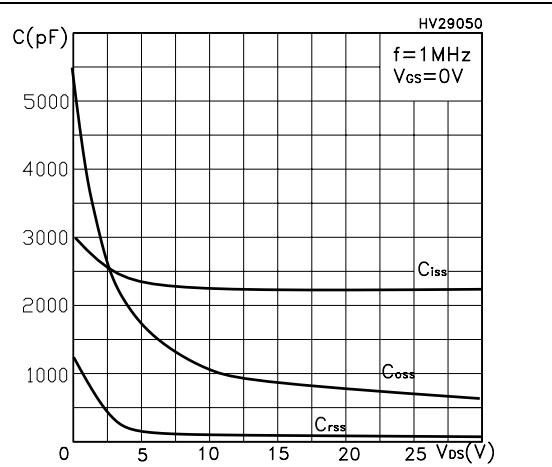
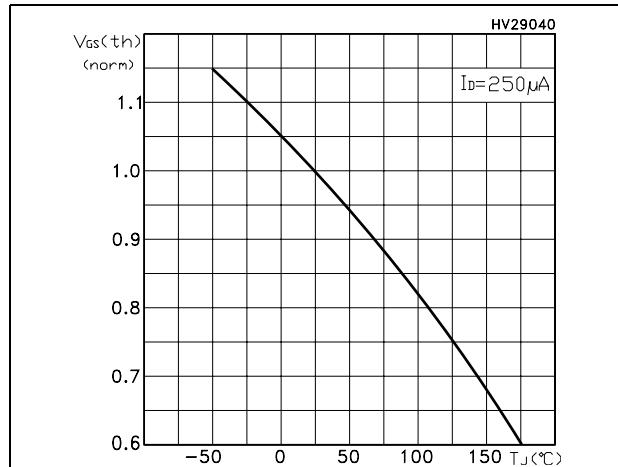
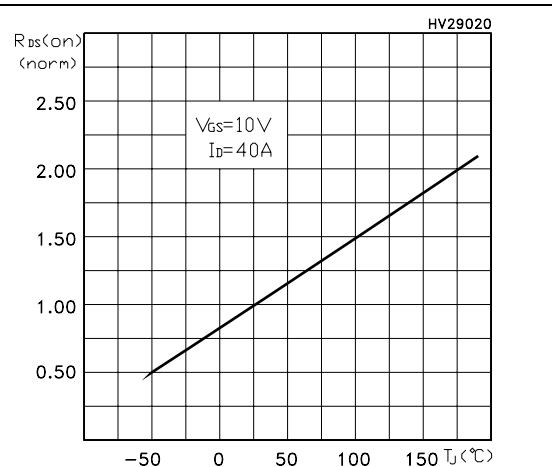
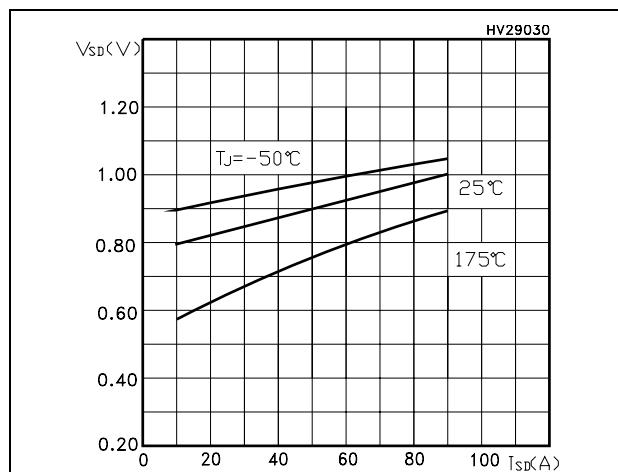


Figure 8. Gate charge vs gate-source voltage**Figure 9. Capacitance variations****Figure 10. Normalized gate threshold voltage vs temperature****Figure 11. Normalized on resistance vs temperature****Figure 12. Source-drain diode forward characteristics**

3 Test circuits

Figure 13. Switching times test circuit for resistive load

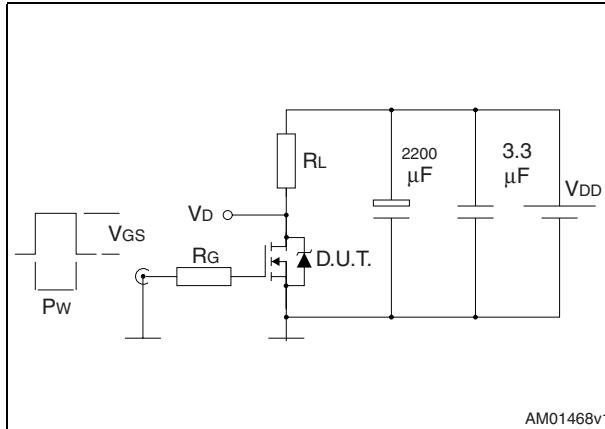


Figure 14. Gate charge test circuit

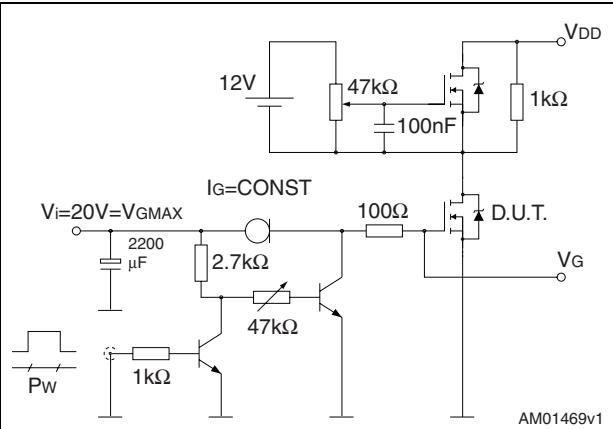


Figure 15. Test circuit for inductive load switching and diode recovery times

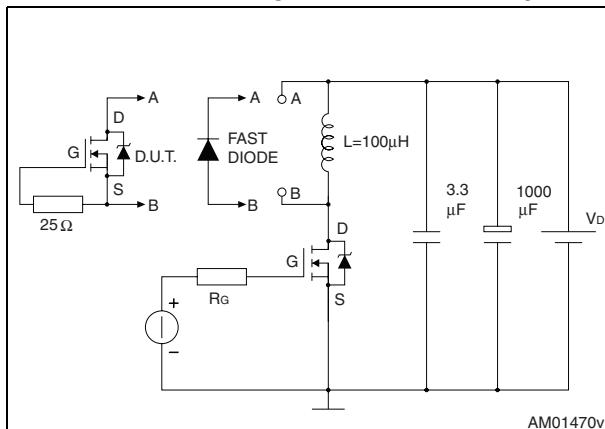


Figure 16. Unclamped inductive load test circuit

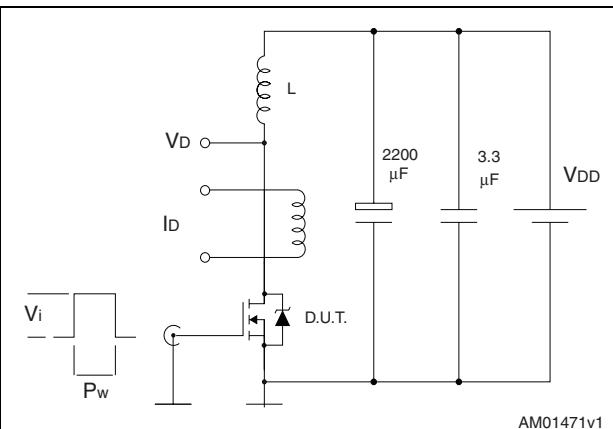


Figure 17. Unclamped inductive waveform

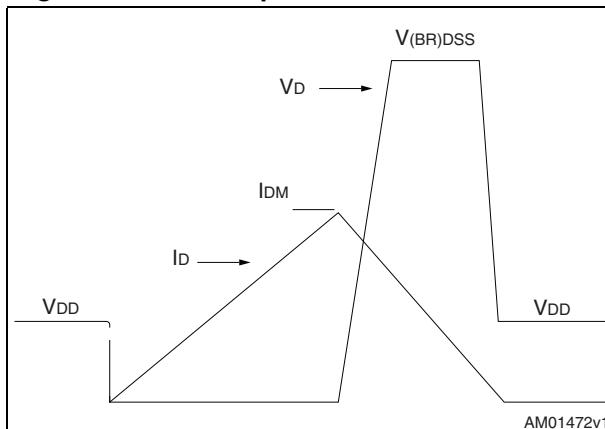
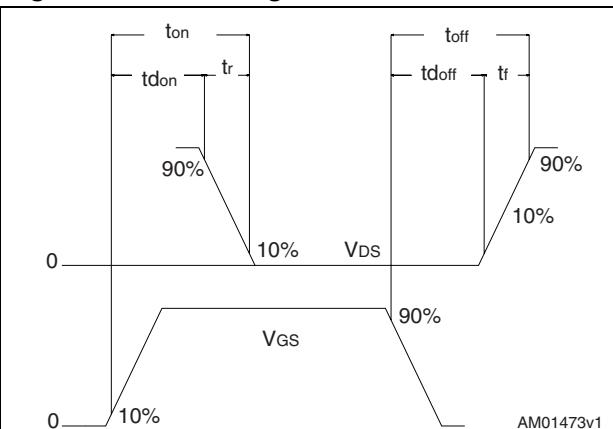


Figure 18. Switching time waveform

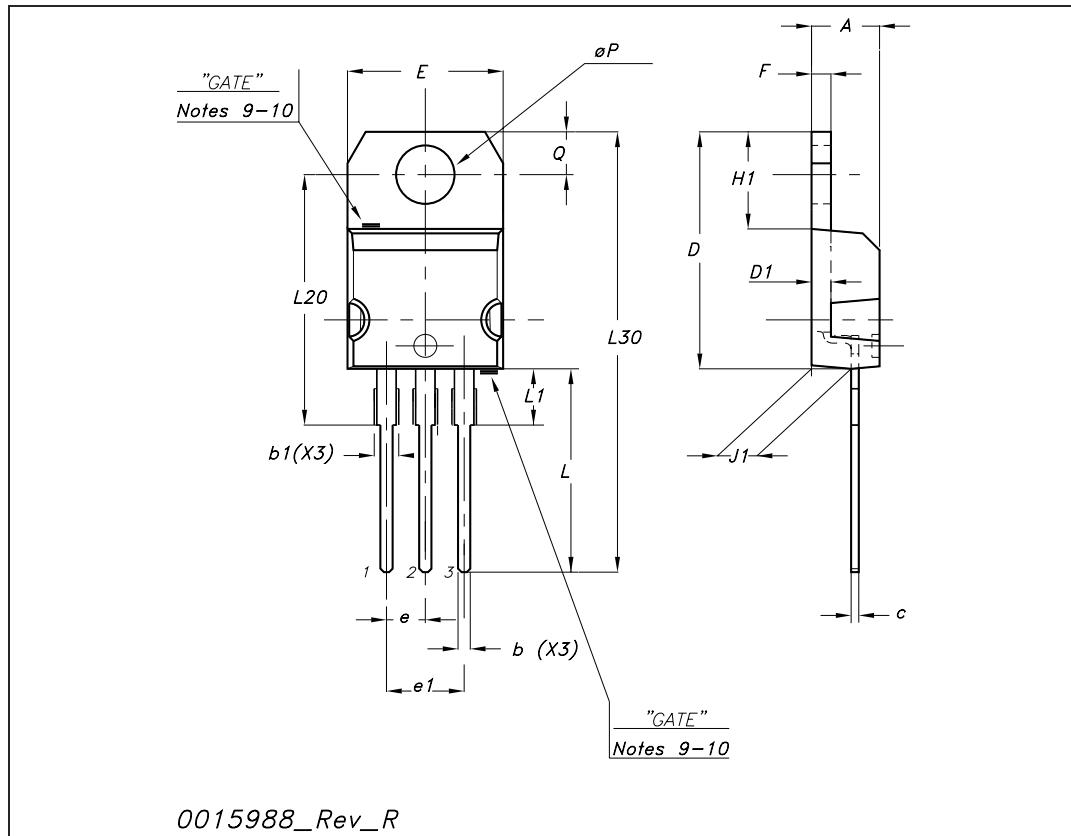


4 Package mechanical data

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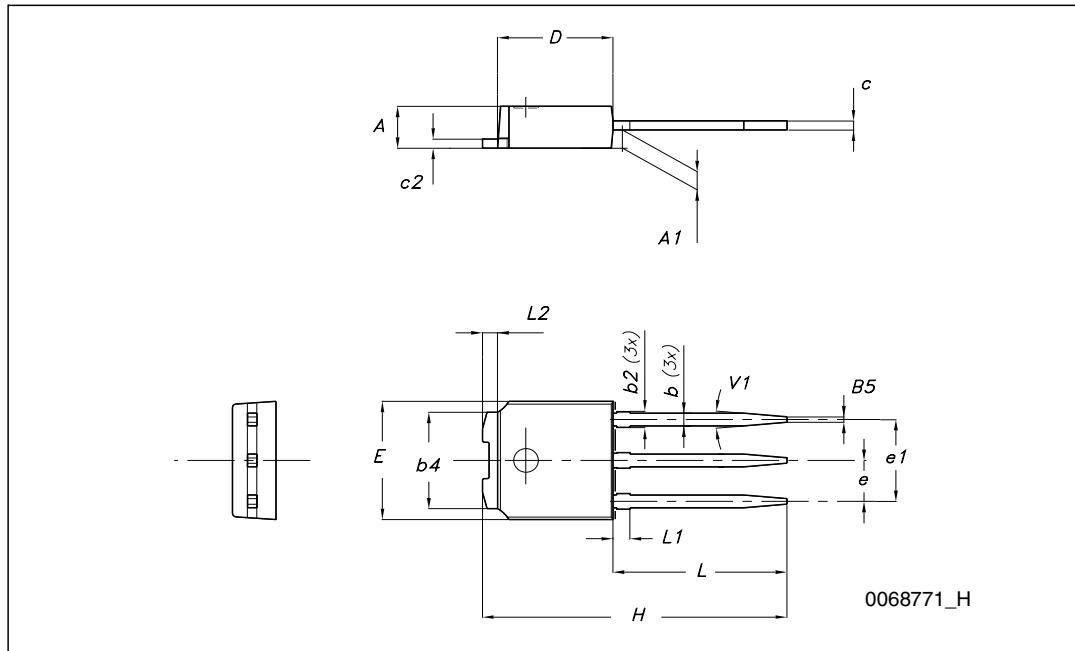
TO-220 mechanical data

Dim	mm			inch		
	Min	Typ	Max	Min	Typ	Max
A	4.40		4.60	0.173		0.181
b	0.61		0.88	0.024		0.034
b1	1.14		1.70	0.044		0.066
c	0.48		0.70	0.019		0.027
D	15.25		15.75	0.6		0.62
D1		1.27			0.050	
E	10		10.40	0.393		0.409
e	2.40		2.70	0.094		0.106
e1	4.95		5.15	0.194		0.202
F	1.23		1.32	0.048		0.051
H1	6.20		6.60	0.244		0.256
J1	2.40		2.72	0.094		0.107
L	13		14	0.511		0.551
L1	3.50		3.93	0.137		0.154
L20		16.40			0.645	
L30		28.90			1.137	
$\emptyset P$	3.75		3.85	0.147		0.151
Q	2.65		2.95	0.104		0.116



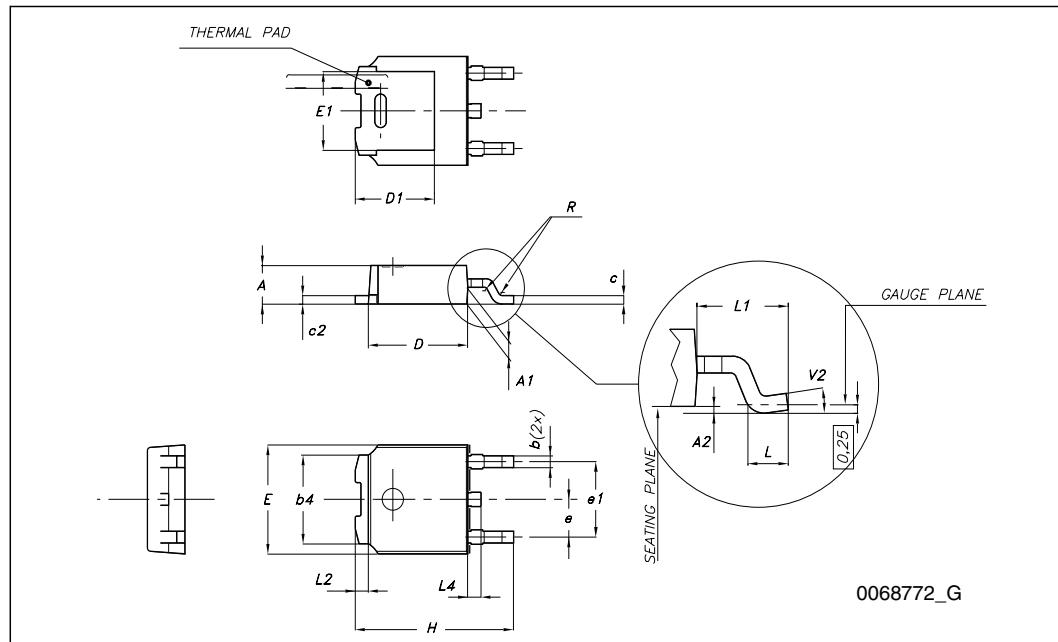
TO-251 (IPAK) mechanical data

DIM.	mm.		
	min.	typ	max.
A	2.20		2.40
A1	0.90		1.10
b	0.64		0.90
b2			0.95
b4	5.20		5.40
c	0.45		0.60
c2	0.48		0.60
D	6.00		6.20
E	6.40		6.60
e		2.28	
e1	4.40		4.60
H		16.10	
L	9.00		9.40
(L1)	0.80		1.20
L2		0.80	
V1		10 °	



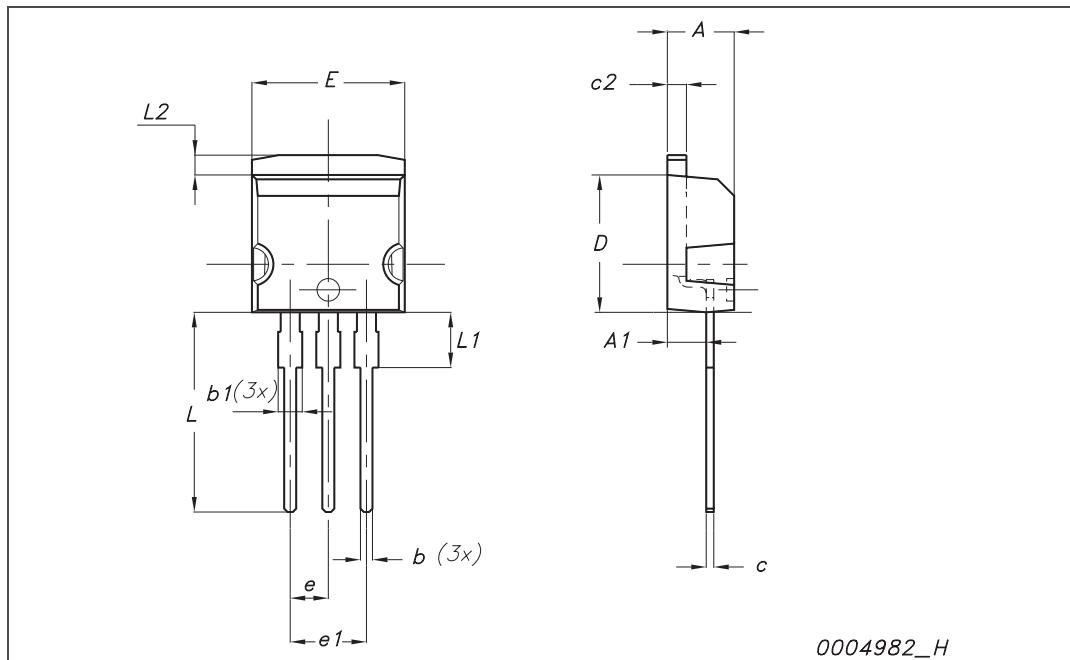
TO-252 (DPAK) mechanical data

DIM.	mm.		
	min.	typ	max.
A	2.20		2.40
A1	0.90		1.10
A2	0.03		0.23
b	0.64		0.90
b4	5.20		5.40
c	0.45		0.60
c2	0.48		0.60
D	6.00		6.20
D1		5.10	
E	6.40		6.60
E1		4.70	
e		2.28	
e1	4.40		4.60
H	9.35		10.10
L	1		
L1		2.80	
L2		0.80	
L4	0.60		1
R		0.20	
V2	0 °		8 °



I²PAK (TO-262) mechanical data

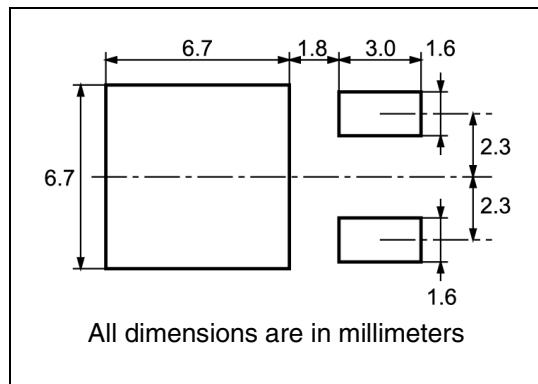
Dim	mm			inch		
	Min	Typ	Max	Min	Typ	Max
A	4.40		4.60	0.173		0.181
A1	2.40		2.72	0.094		0.107
b	0.61		0.88	0.024		0.034
b1	1.14		1.70	0.044		0.066
c	0.49		0.70	0.019		0.027
c2	1.23		1.32	0.048		0.052
D	8.95		9.35	0.352		0.368
e	2.40		2.70	0.094		0.106
e1	4.95		5.15	0.194		0.202
E	10		10.40	0.393		0.410
L	13		14	0.511		0.551
L1	3.50		3.93	0.137		0.154
L2	1.27		1.40	0.050		0.055



0004982_H

5 Packaging mechanical data

DPAK FOOTPRINT



TAPE AND REEL SHIPMENT

REEL MECHANICAL DATA				
DIM.	mm		inch	
	MIN.	MAX.	MIN.	MAX.
A		330		12.992
B	1.5		0.059	
C	12.8	13.2	0.504	0.520
D	20.2		0.795	
G	16.4	18.4	0.645	0.724
N	50		1.968	
T		22.4		0.881

BASE QTY	BULK QTY
2500	2500

TAPE MECHANICAL DATA

DIM.	mm		inch	
	MIN.	MAX.	MIN.	MAX.
A ₀	6.8	7	0.267	0.275
B ₀	10.4	10.6	0.409	0.417
B ₁		12.1		0.476
D	1.5	1.6	0.059	0.063
D ₁	1.5		0.059	
E	1.65	1.85	0.065	0.073
F	7.4	7.6	0.291	0.299
K ₀	2.55	2.75	0.100	0.108
P ₀	3.9	4.1	0.153	0.161
P ₁	7.9	8.1	0.311	0.319
P ₂	1.9	2.1	0.075	0.082
R	40		1.574	
W	15.7	16.3	0.618	0.641

6 Revision history

Table 8. Document revision history

Date	Revision	Changes
29-Nov-2007	1	First release
15-Jul-2008	2	Added new package, mechanical data: I ² PAK
23-Jul-2009	3	R _{DS(on)} values have been revised

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